BPW76A, BPW76B

Vishay Semiconductors



Silicon NPN Phototransistor, RoHS Compliant



BPW76 is a silicon NPN phototransistor with high radiant

sensitivity in hermetically sealed TO-18 package with base

terminal and flat glass window. It is sensitive to visible and

FEATURES

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): Ø 4.7
- · High photo sensitivity
- High radiant sensitivity
- · Suitable for visible and near infrared radiation
- · Fast response times
- Angle of half sensitivity: $\phi = \pm 40^{\circ}$
- · Base terminal connected
- Hermetically sealed package
- Flat glass window
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

· Detector in electronic control and drive circuits

PRODUCT SUMMARY COMPONENT I_{ca} (mA) φ (deg) λ_{0.1} (nm) BPW76A 0.4 to 0.8 ± 40 450 to 1080 BPW76B > 0.6 ± 40 450 to 1080

Note

DESCRIPTION

near infrared radiation.

Test condition see table "Basic Characteristics"

| ORDERING INFORMATION | | | | | | |
|----------------------|-----------|------------------------------|-------|--|--|--|
| ORDERING CODE | PACKAGING | PACKAGE FORM | | | | |
| BPW76A | Bulk | MOQ: 1000 pcs, 1000 pcs/bulk | TO-18 | | | |
| BPW76B | Bulk | MOQ: 1000 pcs, 1000 pcs/bulk | TO-18 | | | |

Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|-------------------------------------|--|-------------------|---------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Collector base voltage | | V _{CBO} | 80 | V | |
| Collector emitter voltage | | V _{CEO} | 70 | V | |
| Emitter base voltage | | V _{EBO} | 5 | V | |
| Collector current | | Ι _C | 50 | mA | |
| Collector peak current | $t_p/T=0.5,t_p\leq 10\;ms$ | I _{CM} | 100 | mA | |
| Total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | Pv | 250 | mW | |
| Junction temperature | | Tj | 125 | °C | |
| Operating temperature range | | T _{amb} | - 40 to + 125 | °C | |
| Storage temperature range | | T _{stg} | - 40 to + 125 | °C | |
| Soldering temperature | $t \le 5 s$ | T _{sd} | 260 | °C | |
| Thermal resistance junction/ambient | Connected with Cu wire, 0.14 mm ² | R _{thJA} | 400 | K/W | |
| Thermal resistance junction/gase | | R _{thJC} | 150 | K/W | |

Note

 T_{amb} = 25 °C, unless otherwise specified





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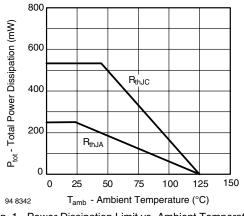


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS | | | | | | |
|--------------------------------------|---|----------------------|------|----------------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Collector emitter breakdown voltage | I _C = 1 mA | V _{(BR)CEO} | 70 | | | V |
| Collector emitter dark current | $V_{CE} = 20 V, E = 0$ | I _{CEO} | | 1 | 100 | nA |
| Collector emitter capacitance | V _{CE} = 5 V, f = 1 MHz, E = 0 | C _{CEO} | | 6 | | pF |
| Angle of half sensitivity | | φ | | ± 40 | | deg |
| Wavelength of peak sensitivity | | λ _p | | 850 | | nm |
| Range of spectral bandwidth | | λ _{0.1} | | 450 to 1080 | | nm |
| Collector emitter saturation voltage | $E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $I_C = 0.1 \text{ mA}$ | V _{CEsat} | | 0.15 | 0.3 | V |
| Turn-on time | V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω | t _{on} | | 6 | | μs |
| Turn-off time | V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω | t _{off} | | 5 | | μs |
| Cut-off frequency | V_S = 5 V, I_C = 5 mA, R_L = 100 Ω | f _c | | 110 | | kHz |

Note

T_{amb} = 25 °C, unless otherwise specified

| TYPE DEDICATED CHARACTERISTICS | | | | | | | |
|--------------------------------|---|--------|-----------------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Collector light current | $\label{eq:eq:entropy} \begin{split} E_{e} = 1 \ mW/cm^2, \lambda = 950 \ nm, \\ V_{CE} = 5 \ V \end{split}$ | BPW76A | I _{ca} | 0.4 | | 0.8 | mA |
| | | BPW76B | I _{ca} | 0.6 | | | mA |

BASIC CHARACTERISTICS

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

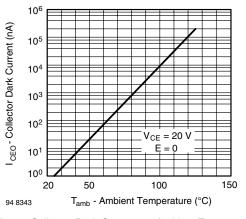


Fig. 2 - Collector Dark Current vs. Ambient Temperature

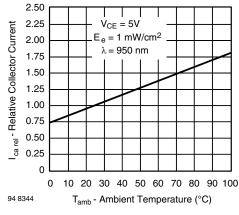


Fig. 3 - Relative Collector Current vs. Ambient Temperature

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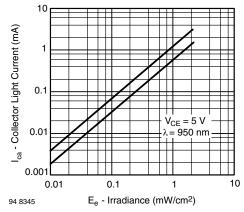


Fig. 4 - Collector Light Current vs. Irradiance

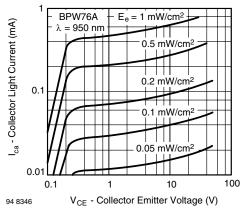


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

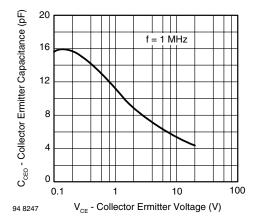


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

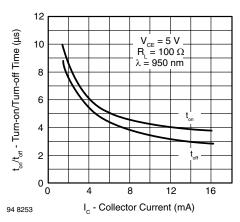


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

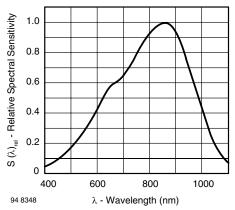


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

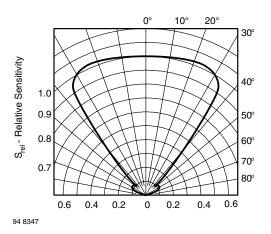


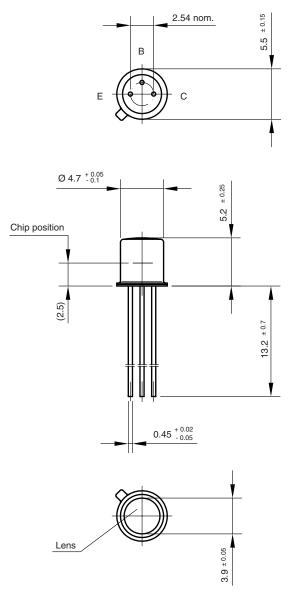
Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

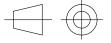


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PACKAGE DIMENSIONS in millimeters





technical drawings according to DIN specifications

Drawing-No.: 6.503-5004.01-4 Issue:1; 01.07.96 96 12175



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